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Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems

Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are Embedded - System On Chip (SoC)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details	
Product Status	Active
Architecture	MCU, FPGA
Core Processor	ARM® Cortex®-M3
Flash Size	256KB
RAM Size	64KB
Peripherals	DMA, POR, WDT
Connectivity	EBI/EMI, Ethernet, I²C, SPI, UART/USART
Speed	100MHz
Primary Attributes	ProASIC®3 FPGA, 200K Gates, 4608 D-Flip-Flops
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-LBGA
Supplier Device Package	256-FPBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a2f200m3f-1fgg256

SmartFusion cSoC Family Product Table

FPGA Fabric	A2F060			A2F200				A2F500			
	TQ144	CS288	FG256	PQ208	CS288	FG256	FG484	PQ208	CS288	FG256	FG484
System Gates	60,000			200,000				500,000			
Tiles (D-flip-flops)	1,536			4,608				11,520			
RAM Blocks (4,608 bits)	8			8				24			
Microcontroller Subsystem (MSS)	**A2F060**			**A2F200**				**A2F500**			
	TQ144	CS288	FG256	PQ208	CS288	FG256	FG484	PQ208	CS288	FG256	FG484
Flash (Kbytes)	128			256				512			
SRAM (Kbytes)	16			64				64			
Cortex-M3 processor with MPU	Yes			Yes				Yes			
10/100 Ethernet MAC	No			Yes				Yes			
External Memory Controller (EMC)	–	26-/16-bit address/data		26-bit address,16-bit data				–	26-/16-bit address/data		
DMA	8 Ch			8 Ch				8 Ch			
I^2C	2			2				2			
SPI	1	2		1	2			1	2		
16550 UART	2			2				2			
32-Bit Timer	2			2				2			
PLL	1			1				1	2	1	2
32 KHz Low Power Oscillator	1			1				1			
100 MHz On-Chip RC Oscillator	1			1				1			
Main Oscillator (32 KHz to 20 MHz)	1			1				1			
Programmable Analog	**A2F060**			**A2F200**				**A2F500**			
	TQ144	CS288	FG256	PQ208	CS288	FG256	FG484	PQ208	CS288	FG256	FG484
ADCs (8-/10-/12-bit SAR)	1			2				2			3
DACs (8-/16-/24-bit sigma-delta)	1			2				2			3
Signal Conditioning Blocks (SCBs)	1			4				4			5
Comparator*	2			8				8			10
Current Monitors*	1			4				4			5
Temperature Monitors*	1			4				4			5
Bipolar High Voltage Monitors*	2			8				8			10

*Note: *These functions share I/O pins and may not all be available at the same time. See the "Analog Front-End Overview" section in the http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=130925 for details.*

Table 2-3 • Recommended Operating Conditions[5,6]

Symbol	Parameter[1]		Commercial	Industrial	Units
T_J	Junction temperature		0 to +85	–40 to +100	°C
VCC [2]	1.5 V DC core supply voltage		1.425 to 1.575	1.425 to 1.575	V
VJTAG	JTAG DC voltage		1.425 to 3.6	1.425 to 3.6	V
VPP	Programming voltage	Programming mode[3]	3.15 to 3.45	3.15 to 3.45	V
		Operation[4]	0 to 3.6	0 to 3.6	V
VCCPLLx	Analog power supply (PLL)		1.425 to 1.575	1.425 to 1.575	V
VCCFPGAIOBx/ VCCMSSIOBx[5]	1.5 V DC supply voltage		1.425 to 1.575	1.425 to 1.575	V
	1.8 V DC supply voltage		1.7 to 1.9	1.7 to 1.9	V
	2.5 V DC supply voltage		2.3 to 2.7	2.3 to 2.7	V
	3.3 V DC supply voltage		3.0 to 3.6	3.0 to 3.6	V
	LVDS differential I/O		2.375 to 2.625	2.375 to 2.625	V
	LVPECL differential I/O		3.0 to 3.6	3.0 to 3.6	V
VCC33A[6]	Analog clean 3.3 V supply to the analog circuitry		3.15 to 3.45	3.15 to 3.45	V
VCC33ADCx[6]	Analog 3.3 V supply to ADC		3.15 to 3.45	3.15 to 3.45	V
VCC33AP[6]	Analog clean 3.3 V supply to the charge pump		3.15 to 3.45	3.15 to 3.45	V
VCC33SDDx[6]	Analog 3.3 V supply to sigma-delta DAC		3.15 to 3.45	3.15 to 3.45	V
VAREFx	Voltage reference for ADC		2.527 to 3.3	2.527 to 3.3	V
VCCRCOSC	Analog supply to the integrated RC oscillator		3.15 to 3.45	3.15 to 3.45	V
VDDBAT	External battery supply		2.7 to 3.63	2.7 to 3.63	V
VCCMAINXTAL[6]	Analog supply to the main crystal oscillator		3.15 to 3.45	3.15 to 3.45	V
VCCLPXTAL[6]	Analog supply to the low power 32 KHz crystal oscillator		3.15 to 3.45	3.15 to 3.45	V
VCCENVM	Embedded nonvolatile memory supply		1.425 to 1.575	1.425 to 1.575	V
VCCESRAM	Embedded SRAM supply		1.425 to 1.575	1.425 to 1.575	V
VCC15A[2]	Analog 1.5 V supply to the analog circuitry		1.425 to 1.575	1.425 to 1.575	V
VCC15ADCx[2]	Analog 1.5 V supply to the ADC		1.425 to 1.575	1.425 to 1.575	V

Notes:

1. *All parameters representing voltages are measured with respect to GND unless otherwise specified.*
2. *The following 1.5 V supplies should be connected together while following proper noise filtering practices: VCC, VCC15A, and VCC15ADCx.*
3. *The Programming temperature range supported is $T_{ambient}$ = 0°C to 85°C.*
4. *VPP can be left floating during operation (not programming mode).*
5. *The ranges given here are for power supplies only. The recommended input voltage ranges specific to each I/O standard are given in Table 2-19 on page 2-23. VCCxxxxIOBx should be at the same voltage within a given I/O bank.*
6. *The following 3.3 V supplies should be connected together while following proper noise filtering practices: VCC33A, VCC33ADCx, VCC33AP, VCC33SDDx, VCCMAINXTAL, and VCCLPXTAL.*

Table 2-14 • Different Components Contributing to Dynamic Power Consumption in SmartFusion cSoCs

Parameter	Definition	Power Supply		Device			Units
		Name	Domain	A2F060	A2F200	A2F500	
PAC24	Current Monitor Power Contribution	See Table 2-93 on page 2-78	–	1.03			mW
PAC25	ABPS Power Contribution	See Table 2-96 on page 2-82	–	0.70			mW
PAC26	Sigma-Delta DAC Power Contribution[2]	See Table 2-98 on page 2-85	–	0.58			mW
PAC27	Comparator Power Contribution	See Table 2-97 on page 2-84	–	1.02			mW
PAC28	Voltage Regulator Power Contribution[3]	See Table 2-99 on page 2-87	–	36.30			mW

Notes:

1. *For a different use of MSS peripherals and resources, refer to SmartPower.*
2. *Assumes Input = Half Scale Operation mode.*
3. *Assumes 100 mA load on 1.5 V domain.*

Table 2-15 • Different Components Contributing to the Static Power Consumption in SmartFusion cSoCs

Parameter	Definition	Power Supply		Device			Units
		Name	Domain	A2F060	A2F200	A2F200	
PDC1	Core static power contribution in SoC mode	VCC	1.5 V	11.10	23.70	37.95	mW
PDC2	Device static power contribution in Standby Mode	See Table 2-8 on page 2-10	–	11.10	23.70	37.95	mW
PDC3	Device static power contribution in Time Keeping mode	See Table 2-8 on page 2-10	3.3 V	33.00	33.00	33.00	µW
PDC7	Static contribution per input pin (standard dependent contribution)	VCCxxxxIOBx/VCC	See Table 2-10 and Table 2-11 on page 2-11.				
PDC8	Static contribution per output pin (standard dependent contribution)	VCCxxxxIOBx/VCC	See Table 2-12 and Table 2-13 on page 2-11.				
PDC9	Static contribution per PLL	VCC	1.5 V	2.55	2.55	2.55	mW

Table 2-16 • eNVM Dynamic Power Consumption

Parameter	Description	Condition	Min.	Typ.	Max.	Units
eNVM System	eNVM array operating power	Idle		795		µA
		Read operation	See Table 2-14 on page 2-12.			
		Erase		900		µA
		Write		900		µA
PNVMCTRL	eNVM controller operating power			20		µW/MHz

User I/O Characteristics

Timing Model

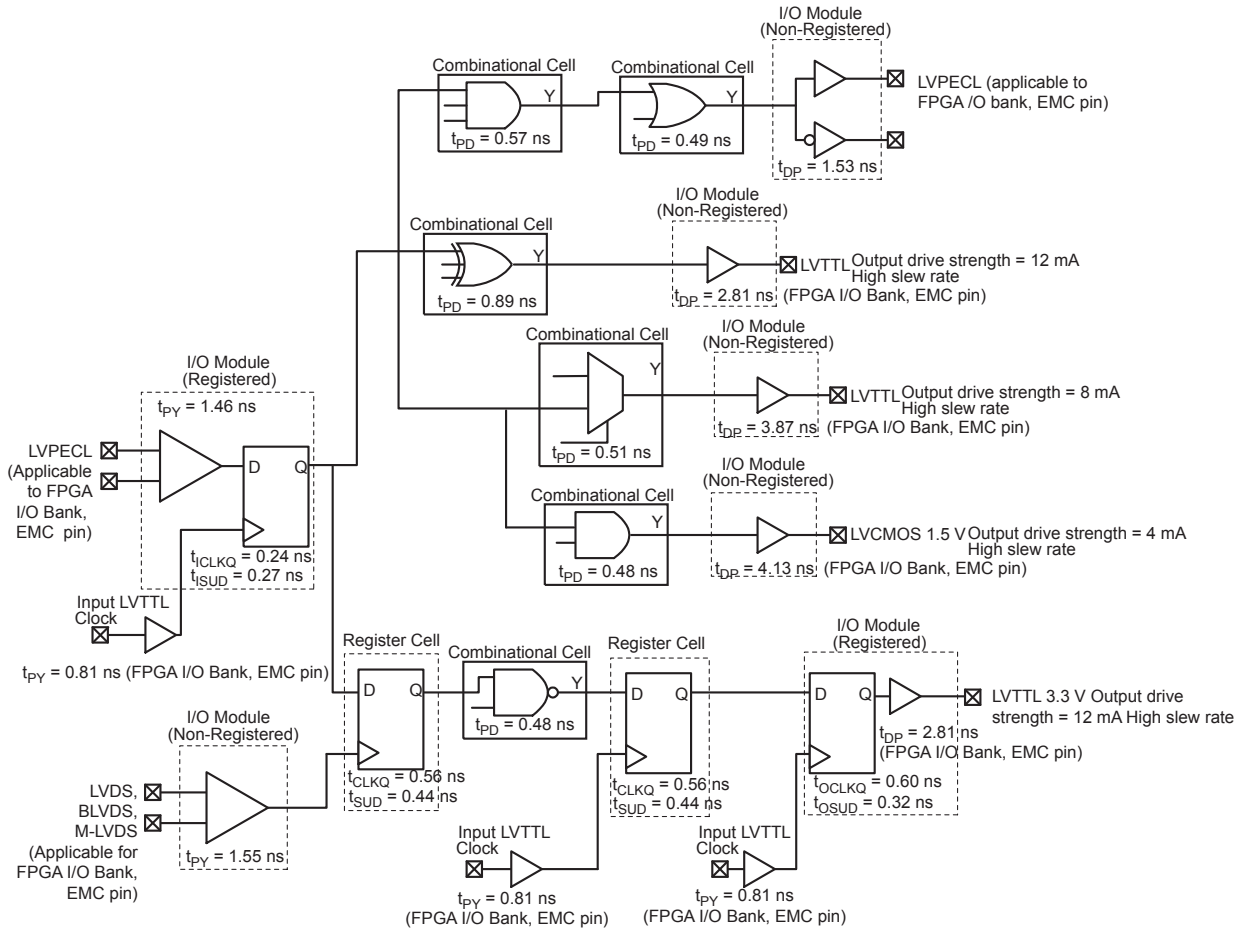

Figure 2-2 • **Timing Model**
Operating Conditions: –1 Speed, Commercial Temperature Range (T_J = 85°C), Worst Case VCC = 1.425 V

I/O Register Specifications

Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Preset

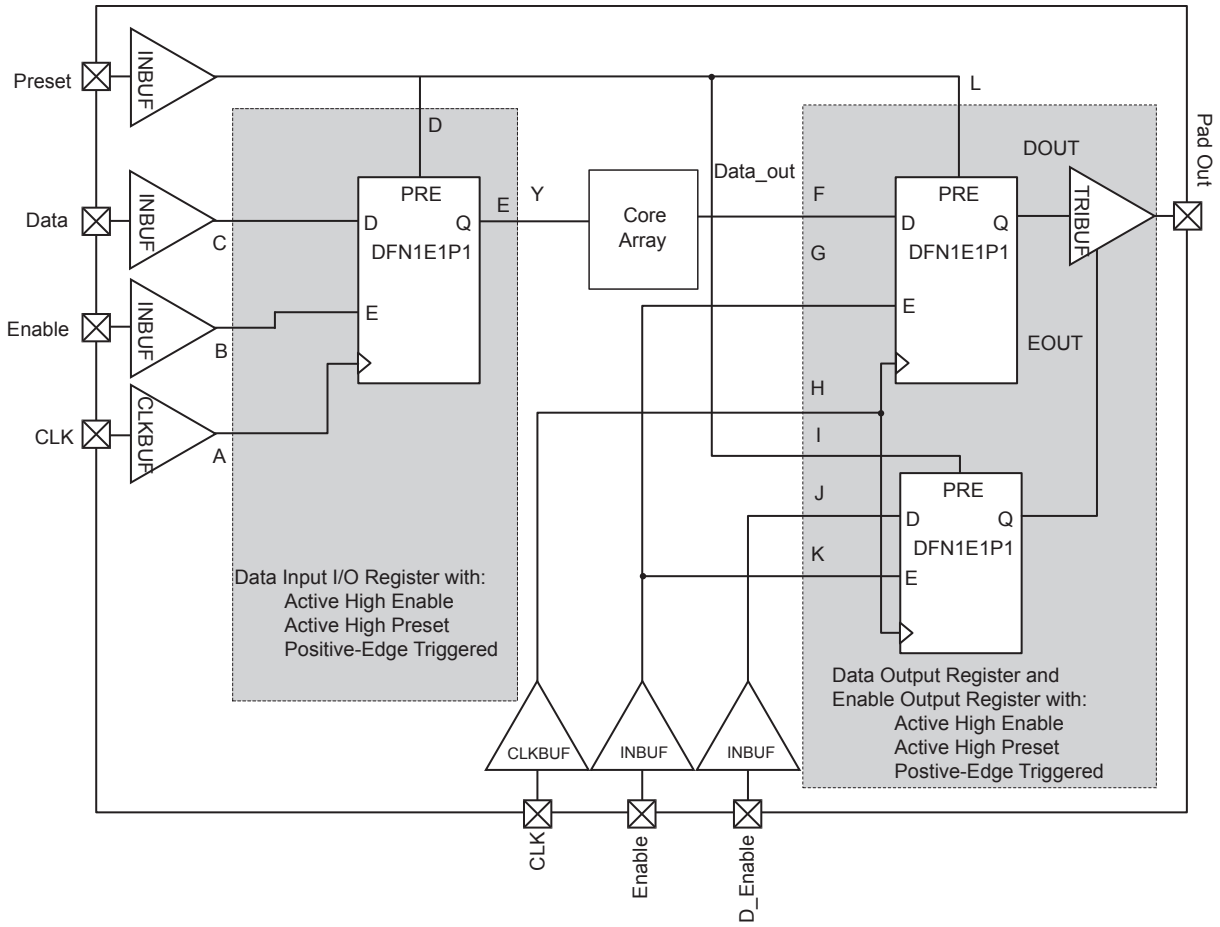

Figure 2-14 • **Timing Model of Registered I/O Buffers with Synchronous Enable and Asynchronous Preset**

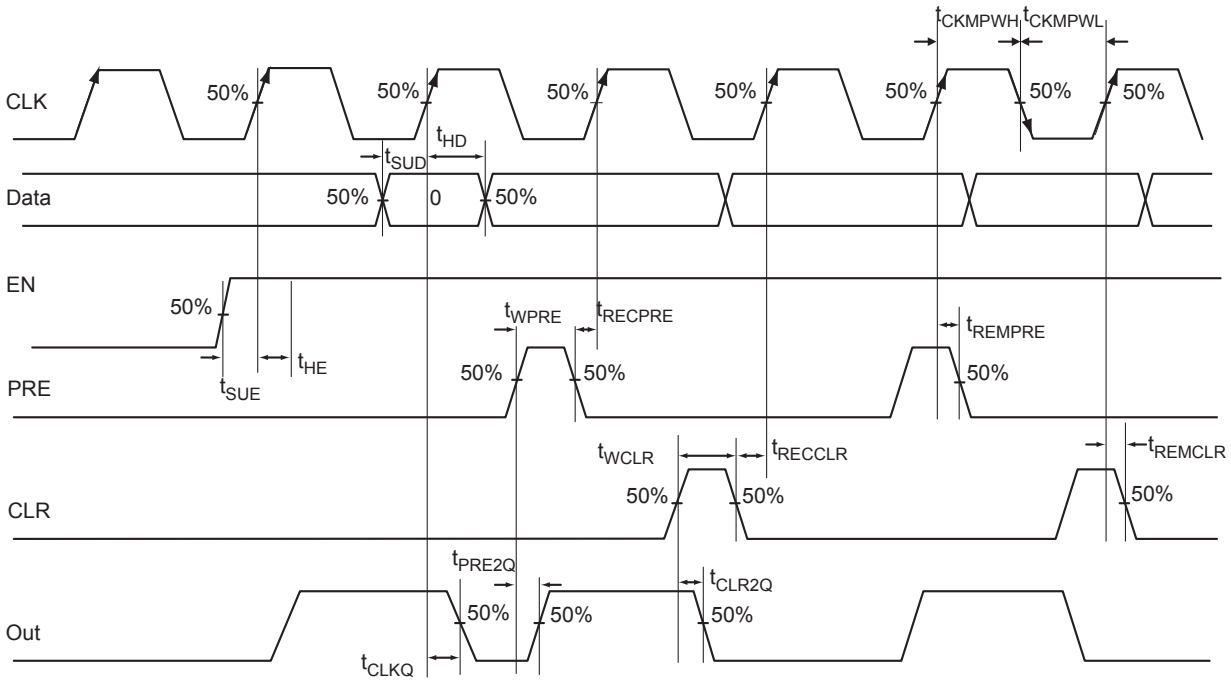

Figure 2-26 • **Timing Model and Waveforms**

Timing Characteristics

Table 2-79 • **Register Delays**
Worst Commercial-Case Conditions: T_J = 85°C, Worst-Case VCC = 1.425 V

Parameter	Description	–1	Std.	Units
t_{CLKQ}	Clock-to-Q of the Core Register	0.56	0.67	ns
t_{SUD}	Data Setup Time for the Core Register	0.44	0.52	ns
t_{HD}	Data Hold Time for the Core Register	0.00	0.00	ns
t_{SUE}	Enable Setup Time for the Core Register	0.46	0.55	ns
t_{HE}	Enable Hold Time for the Core Register	0.00	0.00	ns
t_{CLR2Q}	Asynchronous Clear-to-Q of the Core Register	0.41	0.49	ns
t_{PRE2Q}	Asynchronous Preset-to-Q of the Core Register	0.41	0.49	ns
t_{REMCLR}	Asynchronous Clear Removal Time for the Core Register	0.00	0.00	ns
t_{RECCLR}	Asynchronous Clear Recovery Time for the Core Register	0.23	0.27	ns
t_{REMPRE}	Asynchronous Preset Removal Time for the Core Register	0.00	0.00	ns
t_{RECPRE}	Asynchronous Preset Recovery Time for the Core Register	0.23	0.27	ns
t_{WCLR}	Asynchronous Clear Minimum Pulse Width for the Core Register	0.22	0.22	ns
t_{WPRE}	Asynchronous Preset Minimum Pulse Width for the Core Register	0.22	0.22	ns
t_{CKMPWH}	Clock Minimum Pulse Width High for the Core Register	0.32	0.32	ns
t_{CKMPWL}	Clock Minimum Pulse Width Low for the Core Register	0.36	0.36	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.

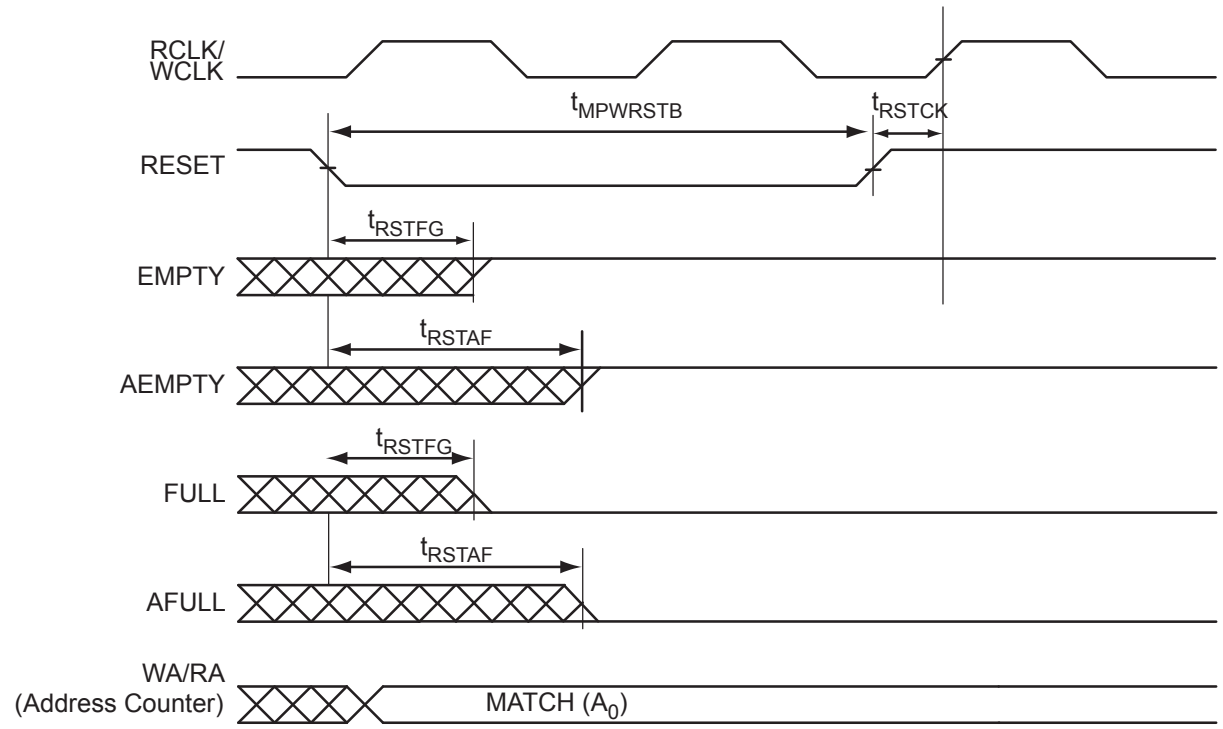

Figure 2-38 • **FIFO Reset**

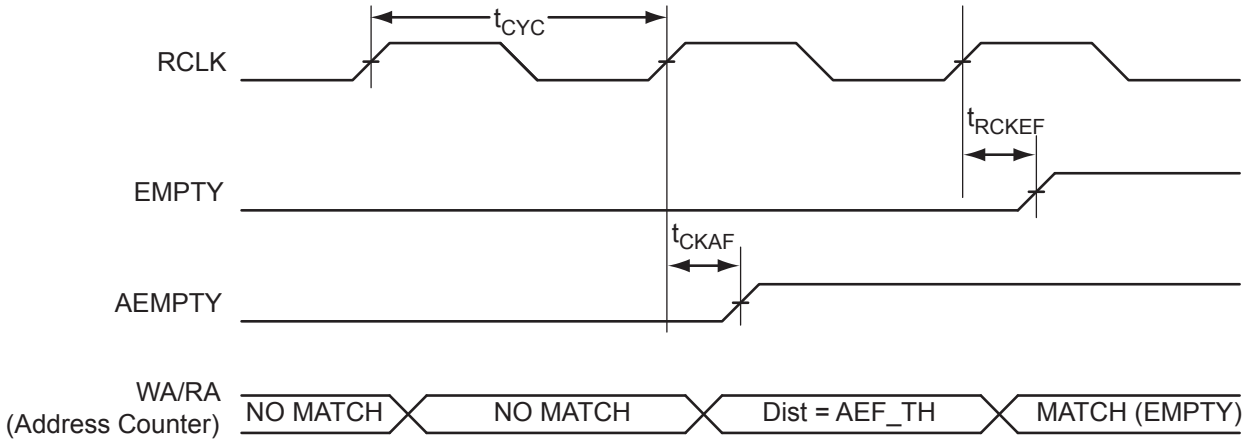

Figure 2-39 • **FIFO EMPTY Flag and AEMPTY Flag Assertion**

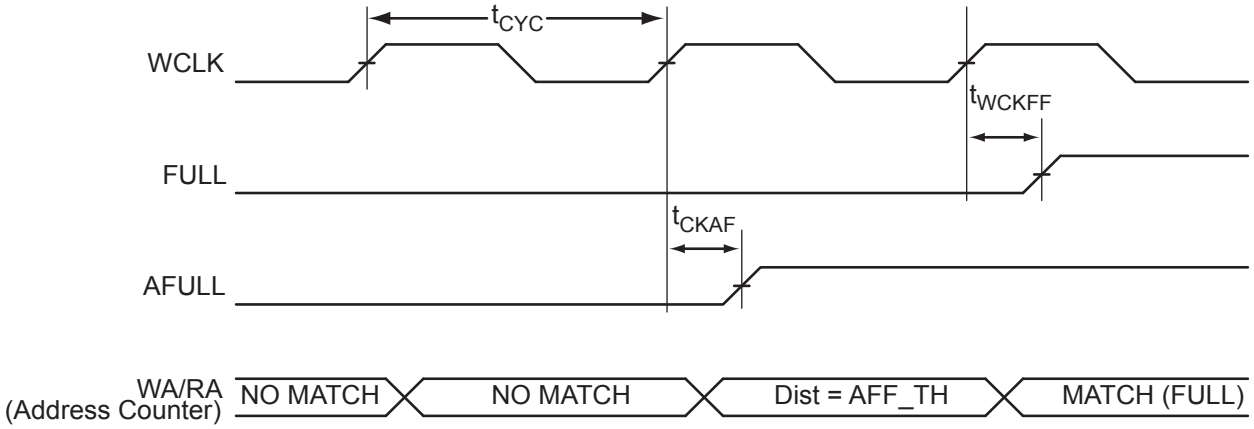

Figure 2-40 • **FIFO FULL Flag and AFULL Flag Assertion**

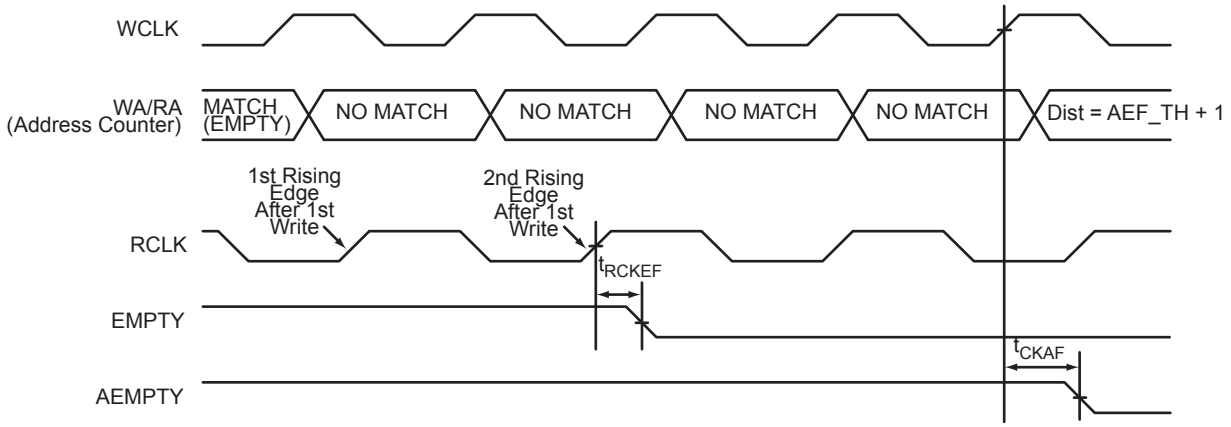

Figure 2-41 • **FIFO EMPTY Flag and AEMPTY Flag Deassertion**

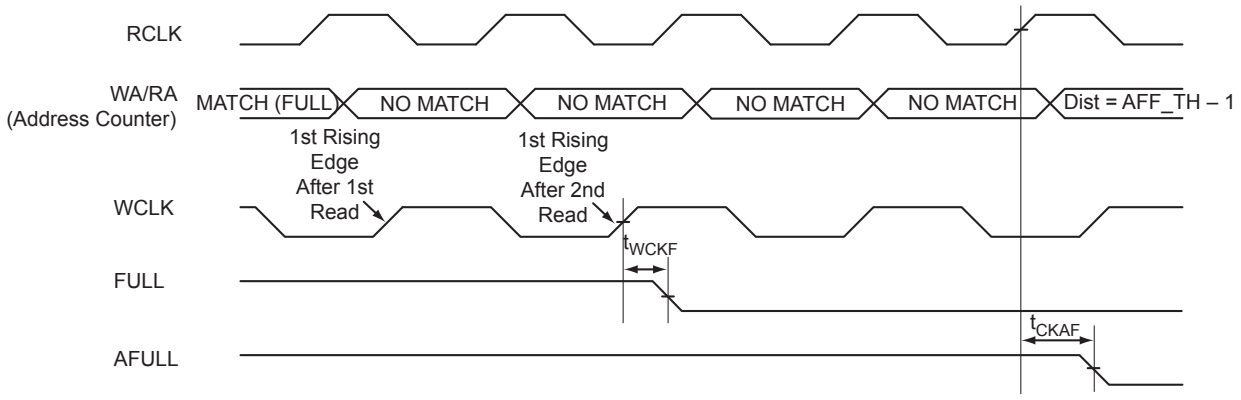

Figure 2-42 • **FIFO FULL Flag and AFULL Flag Deassertion**

***Table 2-98* • Analog Sigma-Delta DAC (continued)**

Specification	Test Conditions	Min.	Typ.	Max.	Units
Sigma-delta DAC power supply current requirements (not including VAREFx)	Input = 0, EN = 1 (operational mode)				
	VCC33SDDx		30	35	µA
	VCC15A		3	5	µA
	Input = Half scale, EN = 1 (operational mode)				
	VCC33SDDx		160	165	µA
	VCC15A		33	35	µA
	Input = Full scale, EN = 1 (operational mode)				
	VCC33SDDx		280	285	µA
	VCC15A		70	75	µA

*Note: *FS is full-scale error, defined as the difference between the actual value that triggers the transition to full-scale and the ideal analog full-scale transition value. Full-scale error equals offset error plus gain error. Refer to the Analog-to-Digital Converter chapter of the SmartFusion Programmable Analog User's Guide for more information.*

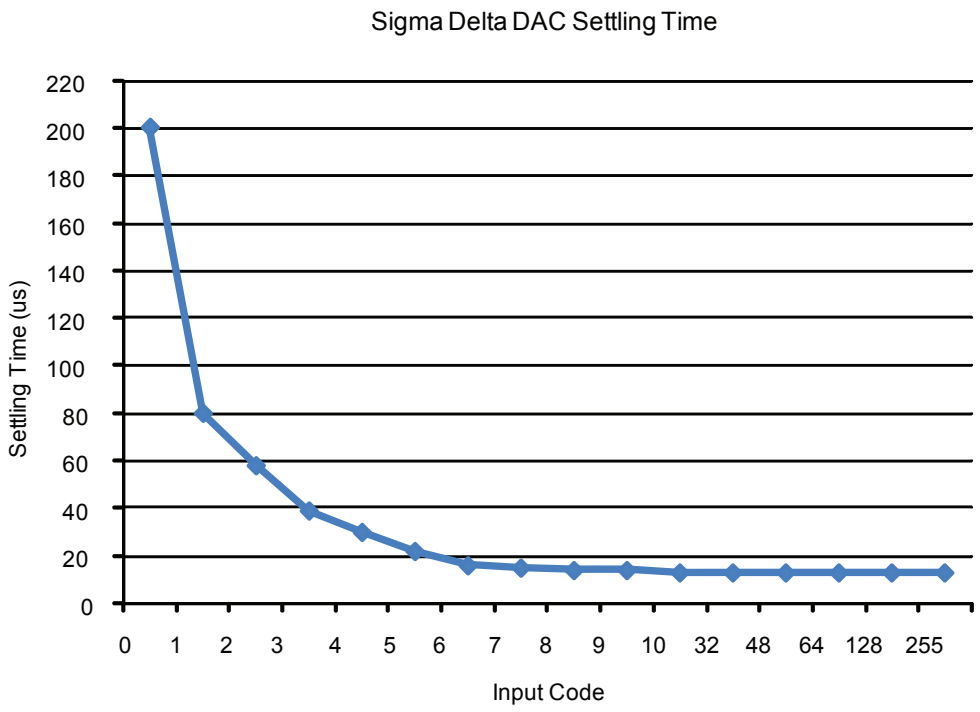

***Figure 2-44* • Sigma-Delta DAC Setting Time**

Voltage Regulator

Table 2-99 • **Voltage Regulator**

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
V_{OUT}	Output voltage	T_J = 25°C		1.425	1.5	1.575	V
V_{OS}	Output offset voltage	T_J = 25°C			11		mV
ICC33A	Operation current	T_J = 25°C	I_{LOAD} = 1 mA		3.4		mA
			I_{LOAD} = 100 mA		11		mA
			I_{LOAD} = 0.5 A		21		mA
ΔV_{OUT}	Load regulation	T_J = 25°C	I_{LOAD} = 1 mA to 0.5 A		5.8		mV
ΔV_{OUT}	Line regulation	T_J = 25°C	VCC33A = 2.97 V to 3.63 V I_{LOAD} = 1 mA		5.3		mV/V
			VCC33A = 2.97 V to 3.63 V I_{LOAD}= 100 mA		5.3		mV/V
			VCC33A = 2.97 V to 3.63 V I_{LOAD} = 500mA		5.3		mV/V
	Dropout voltage[1]	T_J = 25°C	I_{LOAD} = 1 mA		0.63		V
			I_{LOAD} = 100 mA		0.84		V
			I_{LOAD} = 0.5 A		1.35		V
I_{PTBASE}	PTBase current	T_J = 25°C	I_{LOAD} = 1 mA		48		µA
			I_{LOAD} = 100 mA		736		µA
			I_{LOAD} = 0.5 A		12		mA
	Startup time[2]	T_J = 25°C			200		µs

Notes:

1. *Dropout voltage is defined as the minimum VCC33A voltage. The parameter is specified with respect to the output voltage. The specification represents the minimum input-to-output differential voltage required to maintain regulation.*
2. *Assumes 10 µF.*

User-Defined Supply Pins

Name	Type	Polarity/ Bus Size	Description
VAREF0	Input	1	Analog reference voltage for first ADC. The SmartFusion cSoC can be configured to generate a 2.56 V internal reference that can be used by the ADC. While using the internal reference, the reference voltage is output on the VAREFOUT pin for use as a system reference. If a different reference voltage is required, it can be supplied by an external source and applied to this pin. The valid range of values that can be supplied to the ADC is 1.0 V to 3.3 V. When VAREF0 is internally generated, a bypass capacitor must be connected from this pin to ground. The value of the bypass capacitor should be between 3.3 µF and 22 µF, which is based on the needs of the individual designs. The choice of the capacitor value has an impact on the settling time it takes the VAREF0 signal to reach the required specification of 2.56 V to initiate valid conversions by the ADC. If the lower capacitor value is chosen, the settling time required for VAREF0 to achieve 2.56 V will be shorter than when selecting the larger capacitor value. The above range of capacitor values supports the accuracy specification of the ADC, which is detailed in the datasheet. Designers choosing the smaller capacitor value will not obtain as much margin in the accuracy as that achieved with a larger capacitor value. See the Analog-to-Digital Converter (ADC) section in the *SmartFusion Programmable Analog User's Guide* for more information. The SoC Products Group recommends customers use 10 µF as the value of the bypass capacitor. Designers choosing to use an external VAREF0 need to ensure that a stable and clean VAREF0 source is supplied to the VAREF0 pin before initiating conversions by the ADC. To use the internal voltage reference, the VAREFOUT pin must be connected to the appropriate ADC VAREFx input on the PCB. For example, VAREFOUT can be connected to VAREF0 only, if ADC0 alone is used. VAREFOUT can be connected to VAREF1 only, if ADC1 alone is used. VAREFOUT can be connected to VAREF2 only, if ADC2 alone is used. VAREFOUT can be connected to VAREF0, VAREF1 and VAREF2 together, if ADC0, ADC1, and ADC2 all are used.
VAREF1	Input	1	Analog reference voltage for second ADC See "VAREF0" above for more information.
VAREF2	Input	1	Analog reference voltage for third ADC See "VAREF0" above for more.
VAREFOUT	Out	1	Internal 2.56 V voltage reference output. Can be used to provide the two ADCs with a unique voltage reference externally by connecting VAREFOUT to both VAREF0 and VAREF1. To use the internal voltage reference, you must connect the VAREFOUT pin to the appropriate ADC VAREFx input—either the VAREF0 or VAREF1 pin—on the PCB.

JTAG Pins

SmartFusion cSoCs have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). VCC must also be powered for the JTAG state machine to operate, even if the device is in bypass mode; VJTAG alone is insufficient. Both VJTAG and VCC to the SmartFusion cSoC part must be supplied to allow JTAG signals to transition the SmartFusion cSoC. Isolating the JTAG power supply in a separate I/O bank gives greater flexibility with supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned to be used, the VJTAG pin together with the TRSTB pin could be tied to GND.

Name	Type	Polarity/ Bus Size	Description
JTAGSEL	In	1	JTAG controller selection Depending on the state of the JTAGSEL pin, an external JTAG controller will either see the FPGA fabric TAP/auxiliary TAP (High) or the Cortex-M3 JTAG debug interface (Low). The JTAGSEL pin should be connected to an external pull-up resistor such that the default configuration selects the FPGA fabric TAP.
TCK	In	1	Test clock Serial input for JTAG boundary scan, ISP, and UJTAG. The TCK pin does not have an internal pull-up/-down resistor. If JTAG is not used, it is recommended to tie off TCK to GND or V_{JTAG} through a resistor placed close to the FPGA pin. This prevents JTAG operation in case TMS enters an undesired state. Note that to operate at all V_{JTAG} voltages, 500 Ω to 1 kΩ will satisfy the requirements. Refer to Table 5-1 on page 5-11 for more information. Can be left floating when unused.
TDI	In	1	Test data Serial input for JTAG boundary scan, ISP, and UJTAG usage. There is an internal weak pull-up resistor on the TDI pin.
TDO	Out	1	Test data Serial output for JTAG boundary scan, ISP, and UJTAG usage.
TMS	In	HIGH	Test mode select The TMS pin controls the use of the IEEE1532 boundary scan pins (TCK, TDI, TDO, TRST). There is an internal weak pull-up resistor on the TMS pin. Can be left floating when unused.
TRSTB	In	HIGH	Boundary scan reset pin The TRST pin functions as an active low input to asynchronously initialize (or reset) the boundary scan circuitry. There is an internal weak pull-up resistor on the TRST pin. If JTAG is not used, an external pull-down resistor could be included to ensure the TAP is held in reset mode. The resistor values must be chosen from Table 5-1 on page 5-11 and must satisfy the parallel resistance value requirement. The values in Table 5-1 on page 5-11 correspond to the resistor recommended when a single device is used. The values correspond to the equivalent parallel resistor when multiple devices are connected via a JTAG chain. In critical applications, an upset in the JTAG circuit could allow entering an undesired JTAG state. In such cases, it is recommended that you tie off TRST to GND through a resistor placed close to the FPGA pin. The TRSTB pin also resets the serial wire JTAG – debug port (SWJ-DP) circuitry within the Cortex-M3. Can be left floating when unused.

TQ144	
Pin Number	**A2F060 Function**
109	VPP
110	GNDQ
111	GCA1/IO20PDB0V0
112	GCA0/IO20NDB0V0
113	GCB1/IO19PDB0V0
114	GCB0/IO19NDB0V0
115	GCC1/IO18PDB0V0
116	GCC0/IO18NDB0V0
117	VCCFPGAIOB0
118	GND
119	VCC
120	IO14PDB0V0
121	IO14NDB0V0
122	IO13NSB0V0
123	IO11PDB0V0
124	IO11NDB0V0
125	IO09PDB0V0
126	IO09NDB0V0
127	VCCFPGAIOB0
128	GND
129	IO07PDB0V0
130	IO07NDB0V0
131	IO06PDB0V0
132	IO06NDB0V0
133	IO05PDB0V0
134	IO05NDB0V0
135	IO03PDB0V0
136	IO03NDB0V0
137	VCCFPGAIOB0
138	GND
139	VCC
140	IO01PDB0V0
141	IO01NDB0V0
142	IO00PDB0V0
143	IO00NDB0V0
144	GNDQ

Pin No.	CS288		
	A2F060 Function	A2F200 Function	A2F500 Function
F12	EMC_AB[12]/IO10NDB0V0	EMC_AB[12]/IO10NDB0V0	EMC_AB[12]/IO14NDB0V0
F13	GND	GND	GND
F14	GCB1/IO19PPB0V0	GCC1/IO26PPB1V0	GCC1/IO35PPB1V0
F15	GNDQ	GNDQ	GNDQ
F16	VCCFPGAIOB1	VCCFPGAIOB1	VCCFPGAIOB1
F17	GCB0/IO19NPB0V0	IO24NDB1V0	IO33NDB1V0
F19	IO23NDB1V0	GDB1/IO30PDB1V0	GDB1/IO39PDB1V0
F21	GCA2/IO21PDB1V0	GDB0/IO30NDB1V0	GDB0/IO39NDB1V0
G1	IO41NDB5V0	IO67NDB5V0	IO84NDB5V0
G3	GFC2/IO41PDB5V0	GFC2/IO67PDB5V0	GFC2/IO84PDB5V0
G5	NC	GFB1/IO65PDB5V0	GFB1/IO82PDB5V0
G6	EMC_DB[10]/IO43NDB5V0	EMC_DB[10]/IO69NDB5V0	EMC_DB[10]/IO86NDB5V0
G9	NC	GFC0/IO66NPB5V0	GFC0/IO83NPB5V0
G13	GCA0/IO20NPB0V0	GCC0/IO26NPB1V0	GCC0/IO35NPB1V0
G16	NC	GDA0/IO31NDB1V0	GDA0/IO40NDB1V0
G17	IO22NPB1V0	GDC1/IO29PDB1V0	GDC1/IO38PDB1V0
G19	GCC2/IO23PDB1V0	GDC0/IO29NDB1V0	GDC0/IO38NDB1V0
G21	GND	GND	GND
H1	EMC_DB[9]/IO40PPB5V0	EMC_DB[9]/GEC1/IO63PPB5V0	EMC_DB[9]/GEC1/IO80PPB5V0
H3	GND	GND	GND
H5	NC	GFB0/IO65NDB5V0	GFB0/IO82NDB5V0
H6	EMC_DB[7]/IO39PDB5V0	EMC_DB[7]/GEB1/IO62PDB5V0	EMC_DB[7]/GEB1/IO79PDB5V0
H8	GND	GND	GND
H9	VCC	VCC	VCC
H10	GND	GND	GND
H11	VCC	VCC	VCC
H12	GND	GND	GND
H13	VCC	VCC	VCC
H14	GND	GND	GND
H16	NC	GDA1/IO31PDB1V0	GDA1/IO40PDB1V0
H17	NC	GDC2/IO32PPB1V0	GDC2/IO41PPB1V0

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin No.	CS288		
	A2F060 Function	A2F200 Function	A2F500 Function
U5	VCC33SDD0	VCC33SDD0	VCC33SDD0
U6	VCC15A	VCC15A	VCC15A
U7	NC	ABPS3	ABPS3
U8	NC	ADC2	ADC2
U9	NC	VCC33ADC0	VCC33ADC0
U10	GND15ADC0	GND15ADC1	GND15ADC1
U11	VCC33ADC0	VCC33ADC1	VCC33ADC1
U12	ADC10	ADC7	ADC7
U13	ABPS0	ABPS6	ABPS6
U14	GNDTM0	GNDTM1	GNDTM1
U15	SPI_1_CLK/GPIO_26	SPI_1_CLK/GPIO_26	SPI_1_CLK/GPIO_26
U16	SPI_0_CLK/GPIO_18	SPI_0_CLK/GPIO_18	SPI_0_CLK/GPIO_18
U17	SPI_0_SS/GPIO_19	SPI_0_SS/GPIO_19	SPI_0_SS/GPIO_19
U19	GND	GND	GND
U21	SPI_1_DO/GPIO_24	SPI_1_DO/GPIO_24	SPI_1_DO/GPIO_24
V1	NC	MAC_CLK	MAC_CLK
V3	GNDSDD0	GNDSDD0	GNDSDD0
V19	SPI_1_DI/GPIO_25	SPI_1_DI/GPIO_25	SPI_1_DI/GPIO_25
V21	VCCMSSIOB2	VCCMSSIOB2	VCCMSSIOB2
W1	PCAP	PCAP	PCAP
W3	NCAP	NCAP	NCAP
W4	ADC2	CM0	CM0
W5	ADC3	TM0	TM0
W6	ADC4	TM1	TM1
W7	NC	ADC0	ADC0
W8	NC	ADC3	ADC3
W9	NC	GND33ADC0	GND33ADC0
W10	VCC15ADC0	VCC15ADC1	VCC15ADC1
W11	GND33ADC0	GND33ADC1	GND33ADC1
W12	ADC8	ADC5	ADC5
W13	CM0	CM3	CM3

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin Number	PQ208	
	A2F200	A2F500
187	VCCFPGAIOB0	VCCFPGAIOB0
188	GND	GND
189	VCC	VCC
190	EMC_AB[5]/IO06PDB0V0	IO08PDB0V0
191	EMC_AB[4]/IO06NDB0V0	IO08NDB0V0
192	EMC_AB[3]/IO05PDB0V0	GAC1/IO07PDB0V0
193	EMC_AB[2]/IO05NDB0V0	GAC0/IO07NDB0V0
194	EMC_AB[1]/IO04PDB0V0	IO04PDB0V0
195	EMC_AB[0]/IO04NDB0V0	IO04NDB0V0
196	EMC_OEN1_N/IO03PDB0V0	IO03PDB0V0
197	EMC_OEN0_N/IO03NDB0V0	IO03NDB0V0
198	EMC_BYTEN[1]/GAC1/IO02PDB0V0	GAA1/IO02PDB0V0
199	EMC_BYTEN[0]/GAC0/IO02NDB0V0	GAA0/IO02NDB0V0
200	VCCFPGAIOB0	VCCFPGAIOB0
201	GND	GND
202	VCC	VCC
203	EMC_CS1_N/GAB1/IO01PDB0V0	IO01PDB0V0
204	EMC_CS0_N/GAB0/IO01NDB0V0	IO01NDB0V0
205	EMC_RW_N/GAA1/IO00PDB0V0	IO00PDB0V0
206	EMC_CLK/GAA0/IO00NDB0V0	IO00NDB0V0
207	VCCFPGAIOB0	VCCFPGAIOB0
208	GNDQ	GNDQ

Notes:

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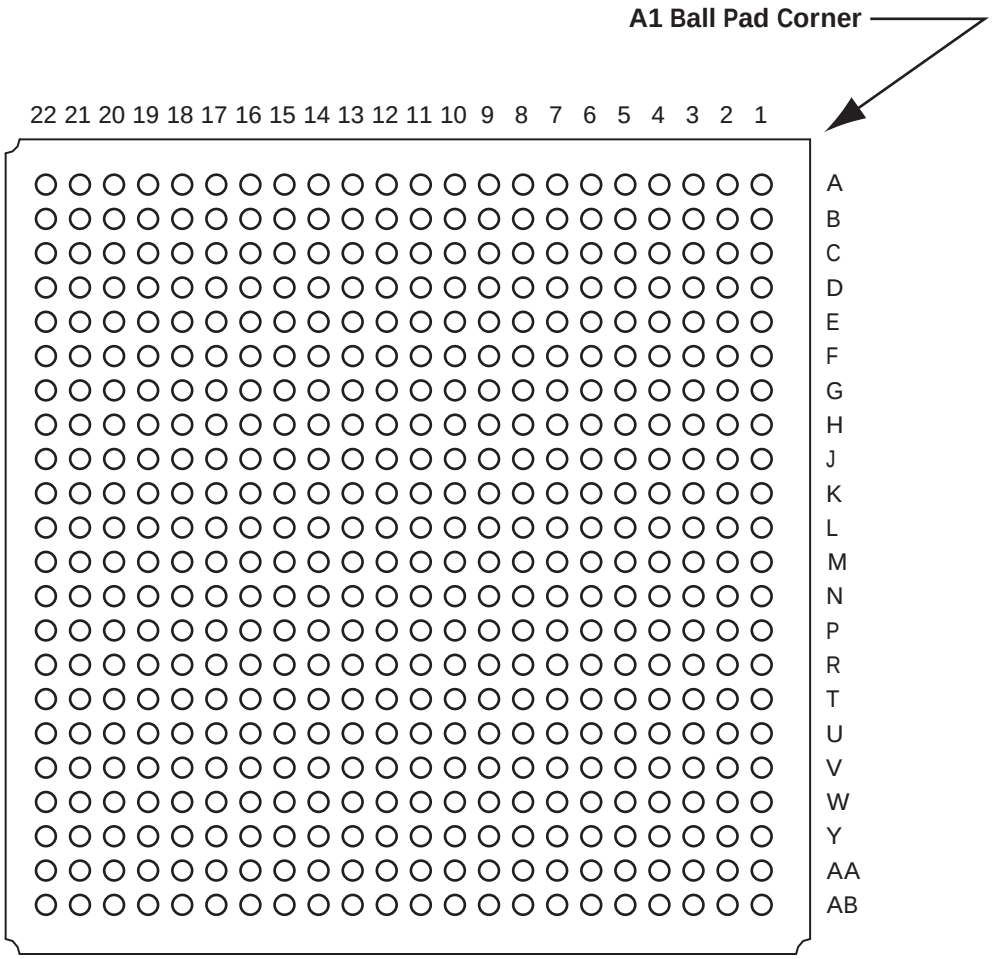
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin No.	FG256		
	A2F060 Function	A2F200 Function	A2F500 Function
A1	GND	GND	GND
A2	VCCFPGAIOB0	VCCFPGAIOB0	VCCFPGAIOB0
A3	EMC_AB[0]/IO04NDB0V0	EMC_AB[0]/IO04NDB0V0	EMC_AB[0]/IO06NDB0V0
A4	EMC_AB[1]/IO04PDB0V0	EMC_AB[1]/IO04PDB0V0	EMC_AB[1]/IO06PDB0V0
A5	GND	GND	GND
A6	EMC_AB[3]/IO05PDB0V0	EMC_AB[3]/IO05PDB0V0	EMC_AB[3]/IO09PDB0V0
A7	EMC_AB[5]/IO06PDB0V0	EMC_AB[5]/IO06PDB0V0	EMC_AB[5]/IO10PDB0V0
A8	VCCFPGAIOB0	VCCFPGAIOB0	VCCFPGAIOB0
A9	GND	GND	GND
A10	EMC_AB[14]/IO11NDB0V0	EMC_AB[14]/IO11NDB0V0	EMC_AB[14]/IO15NDB0V0
A11	EMC_AB[15]/IO11PDB0V0	EMC_AB[15]/IO11PDB0V0	EMC_AB[15]/IO15PDB0V0
A12	GND	GND	GND
A13	EMC_AB[20]/IO14NDB0V0	EMC_AB[20]/IO14NDB0V0	EMC_AB[20]/IO21NDB0V0
A14	EMC_AB[24]/IO16NDB0V0	EMC_AB[24]/IO16NDB0V0	EMC_AB[24]/IO20NDB0V0
A15	VCCFPGAIOB0	VCCFPGAIOB0	VCCFPGAIOB0
A16	GND	GND	GND
B1	EMC_DB[15]/IO45PDB5V0	EMC_DB[15]/GAA2/IO71PDB5V0	EMC_DB[15]/GAA2/IO88PDB5V0
B2	GND	GND	GND
B3	EMC_BYTEN[1]/IO02PDB0V0	EMC_BYTEN[1]/GAC1/IO02PDB0V0	EMC_BYTEN[1]/GAC1/IO07PDB0V0
B4	EMC_OEN0_N/IO03NDB0V0	EMC_OEN0_N/IO03NDB0V0	EMC_OEN0_N/IO08NDB0V0
B5	EMC_OEN1_N/IO03PDB0V0	EMC_OEN1_N/IO03PDB0V0	EMC_OEN1_N/IO08PDB0V0
B6	EMC_AB[2]/IO05NDB0V0	EMC_AB[2]/IO05NDB0V0	EMC_AB[2]/IO09NDB0V0
B7	EMC_AB[4]/IO06NDB0V0	EMC_AB[4]/IO06NDB0V0	EMC_AB[4]/IO10NDB0V0
B8	EMC_AB[9]/IO08PDB0V0	EMC_AB[9]/IO08PDB0V0	EMC_AB[9]/IO13PDB0V0
B9	EMC_AB[12]/IO10NDB0V0	EMC_AB[12]/IO10NDB0V0	EMC_AB[12]/IO14NDB0V0
B10	EMC_AB[13]/IO10PDB0V0	EMC_AB[13]/IO10PDB0V0	EMC_AB[13]/IO14PDB0V0
B11	EMC_AB[16]/IO12NDB0V0	EMC_AB[16]/IO12NDB0V0	EMC_AB[16]/IO17NDB0V0
B12	EMC_AB[18]/IO13NDB0V0	EMC_AB[18]/IO13NDB0V0	EMC_AB[18]/IO18NDB0V0
B13	EMC_AB[21]/IO14PDB0V0	EMC_AB[21]/IO14PDB0V0	EMC_AB[21]/IO21PDB0V0
B14	EMC_AB[25]/IO16PDB0V0	EMC_AB[25]/IO16PDB0V0	EMC_AB[25]/IO20PDB0V0
B15	GND	GND	GND

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

FG484



Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.

Pin Number	FG484	
	A2F200 Function	A2F500 Function
F17	NC	IO25PPB1V0
F18	VCCFPGAIOB1	VCCFPGAIOB1
F19	IO23NDB1V0	IO28NDB1V0
F20	NC	IO31PDB1V0
F21	NC	IO31NDB1V0
F22	IO22PDB1V0	IO32PDB1V0
G1	GND	GND
G2	GFB0/IO65NPB5V0	GFB0/IO82NPB5V0
G3	EMC_DB[9]/GEC1/IO63PDB5V0	EMC_DB[9]/GEC1/IO80PDB5V0
G4	GFC1/IO66PPB5V0	GFC1/IO83PPB5V0
G5	EMC_DB[11]/IO69PPB5V0	EMC_DB[11]/IO86PPB5V0
G6	GNDQ	GNDQ
G7	NC	NC
G8	GND	GND
G9	VCCFPGAIOB0	VCCFPGAIOB0
G10	GND	GND
G11	VCCFPGAIOB0	VCCFPGAIOB0
G12	GND	GND
G13	VCCFPGAIOB0	VCCFPGAIOB0
G14	GND	GND
G15	VCCFPGAIOB0	VCCFPGAIOB0
G16	GNDQ	GNDQ
G17	NC	IO26PDB1V0
G18	NC	IO26NDB1V0
G19	GCA2/IO23PDB1V0	GCA2/IO28PDB1V0 *
G20	IO24NDB1V0	IO33NDB1V0
G21	GCB2/IO24PDB1V0	GCB2/IO33PDB1V0
G22	GND	GND
H1	EMC_DB[7]/GEB1/IO62PDB5V0	EMC_DB[7]/GEB1/IO79PDB5V0
H2	VCCFPGAIOB5	VCCFPGAIOB5
H3	EMC_DB[8]/GEC0/IO63NDB5V0	EMC_DB[8]/GEC0/IO80NDB5V0
H4	GND	GND
H5	GFC0/IO66NPB5V0	GFC0/IO83NPB5V0
H6	GFA1/IO64PDB5V0	GFA1/IO81PDB5V0

Notes:

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